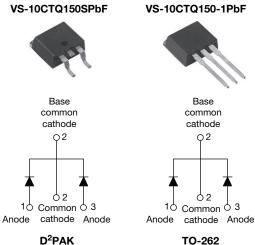


**Vishay Semiconductors** 

## High Performance Schottky Rectifier, 2 x 5 A



TO-262

PRODUCT SUMMARY	
Package	D <sup>2</sup> PAK, TO-262
I <sub>F(AV)</sub>	2 x 5 A
V <sub>R</sub>	150 V
V <sub>F</sub> at I <sub>F</sub>	0.93 V
I <sub>RM</sub>	7 mA at 125 °C
T <sub>J</sub> max.	175 °C
Diode variation	Common cathode
E <sub>AS</sub>	5 mJ

#### **FEATURES**

- 175 °C T<sub>J</sub> operation
- · Center tap configuration
- · Low forward voltage drop
- High frequency operation
- RoHS • High purity, high temperature epoxy COMPLIANT HALOGEN encapsulation for enhanced mechanical FREE strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	10	A		
V <sub>RRM</sub>		150	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	620	A		
V <sub>F</sub>	5 $A_{pk}$ , $T_J$ = 125 °C (per leg)	0.73	V		
TJ	Range	-55 to +175	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-10CTQ150SPbF VS-10CTQ150-1PbF	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	150	V		
Maximum working peak reverse voltage	V <sub>RWM</sub>	150	V		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average per leg	1	50 % duty cycle at $T_{\rm C}$ = 155 °C, rectangular waveform				5	۸
forward current, see fig. 5 per device	$ I_{F(AV)}$ 50 % duty cycle at $I_C = 155$ °C, rectangular waveform		, rectangular wavelonn	10	A		
Maximum peak one cycle non-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated load	620			
surge current per leg, see fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	115	A		
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_J = 25 \text{ °C}, I_{AS} = 1 \text{ A}, L = 10 \text{ mH}$	1	5	mJ		
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero Frequency limited by T <sub>J</sub> maximu		1	А		

Revision: 20-May-14

Document Number: 94116

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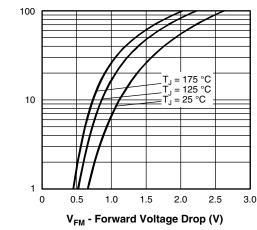
ELECTRICAL SPECIFICATIONS					-	
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		5 A	T <sub>1</sub> = 25 °C	0.93	- V mA V	
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	10 A	1j=25 0	1.10		
See fig. 1	VFM ()	5 A	T <sub>1</sub> = 125 °C	0.73		
		10 A	1j = 125 C	0.86		
Maximum reverse leakage current per leg	I <sub>BM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C		0.05	mA	
See fig. 2	IRM (")	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	7		
Threshold voltage	V <sub>F(TO)</sub>	(F(TO) T T. maximum		0.468	V	
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		28	mΩ	
Maximum junction capacitance per leg	CT	$V_R$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		200	pF	
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 m	m from package body	8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs	

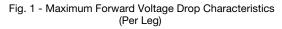
#### Note

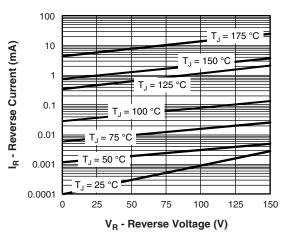
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

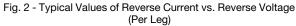
THERMAL - MECH	ANICAL SP	ECIFICAT	IONS			
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and stor temperature range	age	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C	
Maximum thermal resistance, junction to case per leg		P				
Maximum thermal resistance, junction to case per package		– R <sub>thJC</sub>	DC operation	1.75	°C/W	
Typical thermal resistance, case to heatsink (only for T	Typical thermal resistance, case to heatsink (only for TO-220)		Mounting surface, smooth and greased	0.50		
Approximate weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf · cm	
	maximum			12 (10)	(lbf · in)	
Marking davice			Case style D <sup>2</sup> PAK	10CTQ1	50S	
Marking device			Case style TO-262	10CTQ1	50-1	











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## VS-10CTQ150SPbF, VS-10CTQ150-1PbF

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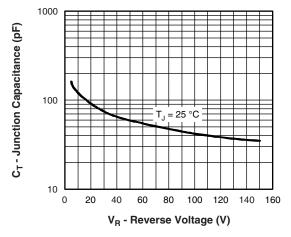


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

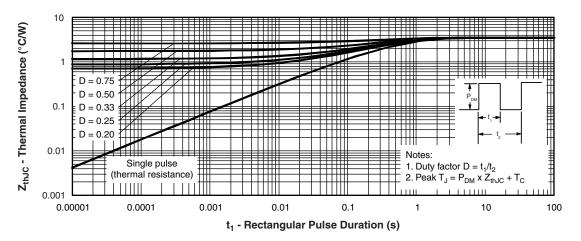


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

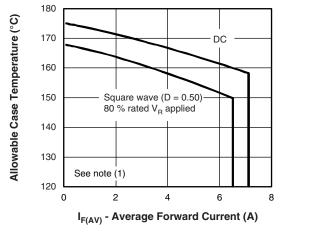


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

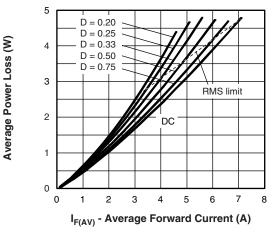


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

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## VS-10CTQ150SPbF, VS-10CTQ150-1PbF

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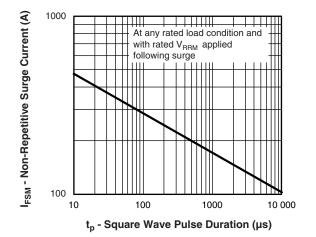


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

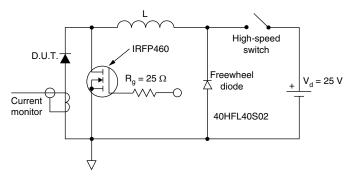


Fig. 8 - Unclamped Inductive Test Circuit

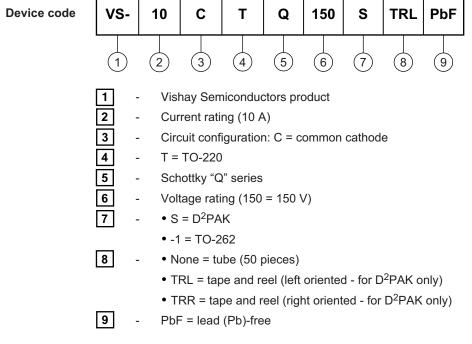
#### Note

 $^{(1)}$  Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};$ Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6); Pd\_{REV} = Inverse power loss =  $V_{R1} \times I_R (1 - D); I_R$  at  $V_{R1} = 10 \text{ V}$  VS-С т PbF 10 Q 150 S TRL

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### **ORDERING INFORMATION TABLE**

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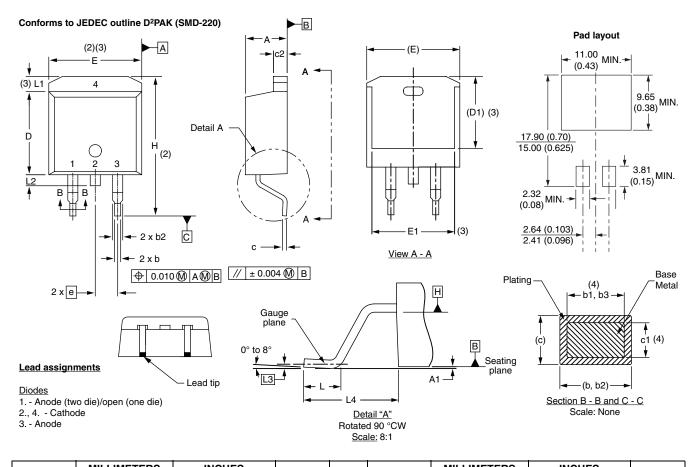
LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95014
Part marking information	www.vishay.com/doc?95008
Packaging information	www.vishay.com/doc?95032

Vishay High Power Products

## D<sup>2</sup>PAK, TO-262

### DIMENSIONS FOR D<sup>2</sup>PAK in millimeters and inches

SHA



SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

<sup>(7)</sup> Outline conforms to JEDEC outline TO-263AB

#### Notes

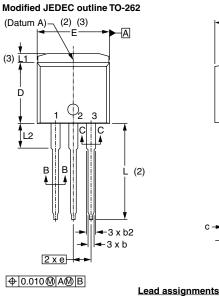
- <sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$  Thermal pad contour optional within dimension E, L1, D1 and E1
- <sup>(4)</sup> Dimension b1 and c1 apply to base metal only
- <sup>(5)</sup> Datum A and B to be determined at datum plane H
- <sup>(6)</sup> Controlling dimension: inch

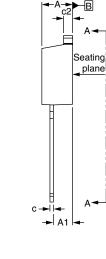
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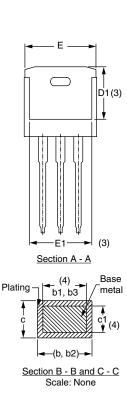
D<sup>2</sup>PAK, TO-262



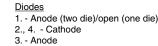
### DIMENSIONS FOR TO-262 in millimeters and inches







Lead tip



SYMBOL -	MILLIM	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100	BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

#### Notes

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- <sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Controlling dimension: inches

<sup>(6)</sup> Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

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